

TOSHIBA Photocoupler Photorelay

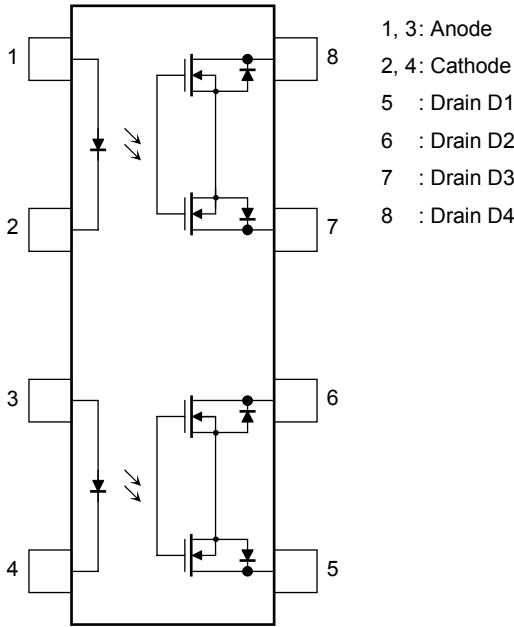
TLP4202G

Telecommunication
Measurement Equipment
Security Equipment
FA

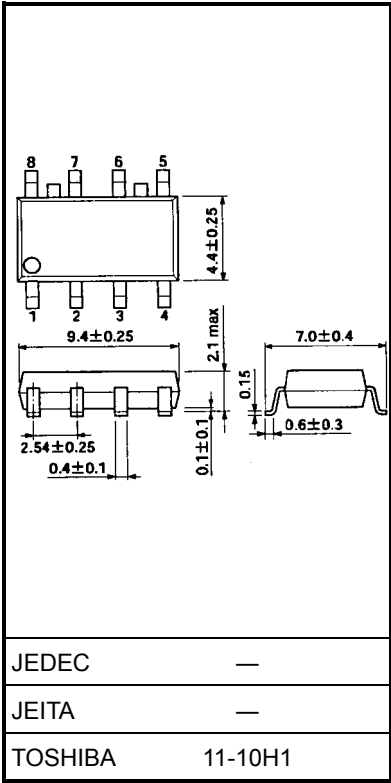
The Toshiba TLP4202G consists of an aluminum gallium arsenide infrared emitting diode optically coupled to a photo-MOSFET in a SOP package. This 2-form-B (NC) photorelay features a withstanding voltage of 350 V.

- 8-pin SOP (2.54SOP8): Height = 2.1 mm, pitch = 2.54 mm
- Normally closed (2-form-B) device
- Peak off-state voltage: 350 V (min)
- Trigger LED current: 3 mA (max)
- On-state current: 90 mA (max)
- On-state resistance: 50 Ω (max)
- Isolation voltage: 1500 Vrms (min)
- UL Recognized: UL1577, File No. E67349

Pin Configuration (top view)



Unit: mm



Weight: 0.2 g (typ.)

Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit
LED	Forward current	I_F	50	mA
	Forward current derating ($T_a \geq 25^\circ\text{C}$)	$\Delta I_F/^\circ\text{C}$	-0.5	mA/°C
	Peak forward current (100 μs pulse, 100 pps)	I_{FP}	1	A
	Reverse voltage	V_R	5	V
	Junction temperature	T_j	125	°C
Detector	Off-state output terminal voltage	V_{OFF}	350	V
	On-state current	I_{ON}	90	mA
	On-state current derating ($T_a \geq 25^\circ\text{C}$)	$\Delta I_{ON}/^\circ\text{C}$	-0.9	mA/°C
	Junction temperature	T_j	125	°C
Storage temperature range		T_{stg}	-55 to 125	°C
Operating temperature range		T_{opr}	-40 to 85	°C
Lead soldering temperature (10 s)		T_{sol}	260	°C
Isolation voltage (AC, 1 min, R.H. $\leq 60\%$) (Note 1)		BV_S	1500	Vrms

Note 1: Pins 1, 2, 3 and 4 are shorted together, and pins 5, 6, 7 and 8 are shorted together.

Recommended Operating Conditions

Characteristics	Symbol	Min	Typ.	Max	Unit
Supply voltage	V_{DD}	—	—	280	V
Forward current	I_F	5	—	25	mA
On-state current	I_{ON}	—	—	90	mA
Operating temperature	T_{opr}	-20	—	65	°C

Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
LED	Forward voltage	V_F	$I_F = 10\text{ mA}$	1.0	1.15	1.3	V
	Reverse current	I_R	$V_R = 5\text{ V}$	—	—	10	μA
	Capacitance	C_T	$V = 0, f = 1\text{ MHz}$	—	30	—	pF
Detector	Off-state current	I_{OFF}	$V_{OFF} = 350\text{ V}, I_F = 5\text{ mA}$	—	—	1	μA
	Capacitance	C_{OFF}	$V = 0, f = 1\text{ MHz}, I_F = 5\text{ mA}$	—	30	—	pF

Coupled Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Trigger LED current	I_{FC}	$I_{OFF} = 10\text{ }\mu\text{A}$	—	1	3	mA
Return LED current	I_{FT}	$I_{ON} = 90\text{ mA}$	0.1	—	—	mA
On-state resistance	R_{ON}	$I_{ON} = 90\text{ mA}$	—	27	50	Ω

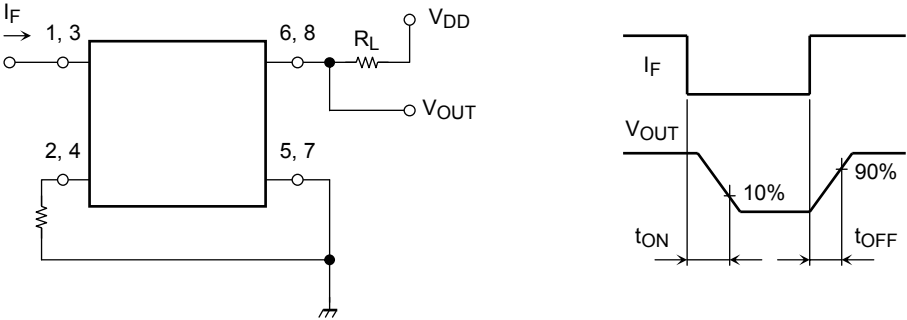
Isolation Characteristics (Ta = 25°C)

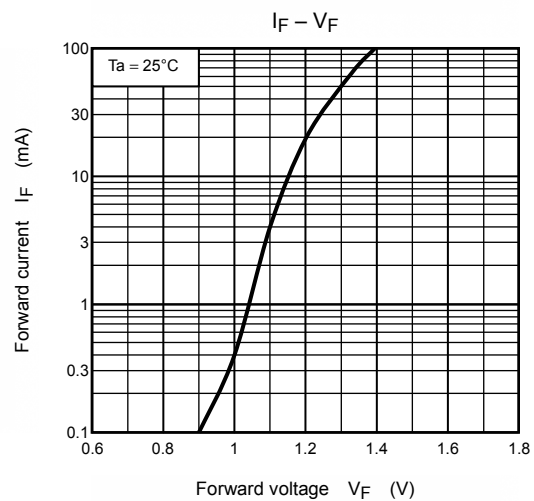
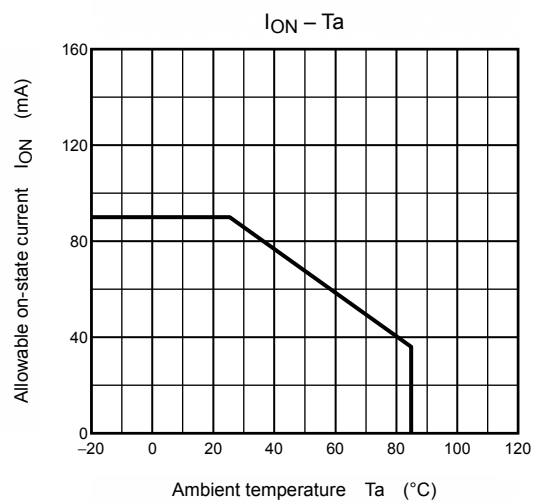
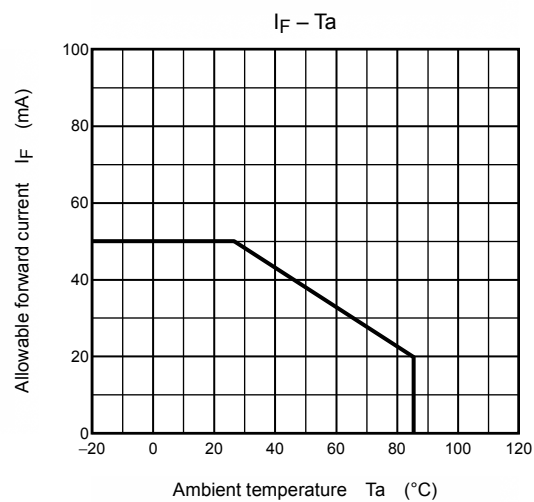
Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Capacitance input to output	C_S	$V_S = 0, f = 1 \text{ MHz}$	—	0.8	—	pF
Isolation resistance	R_S	$V_S = 500 \text{ V}, \text{R.H.} \leq 60\%$	5×10^{10}	10^{14}	—	Ω
Isolation voltage	BV_S	AC, 1 min	1500	—	—	Vrms
		AC, 1 s, in oil	—	3000	—	
		DC, 1 min, in oil	—	3000	—	Vdc

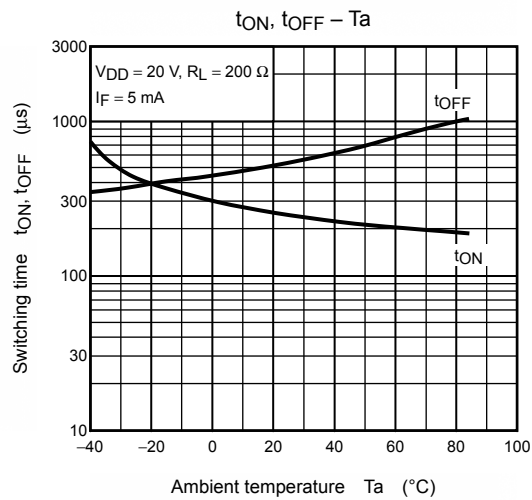
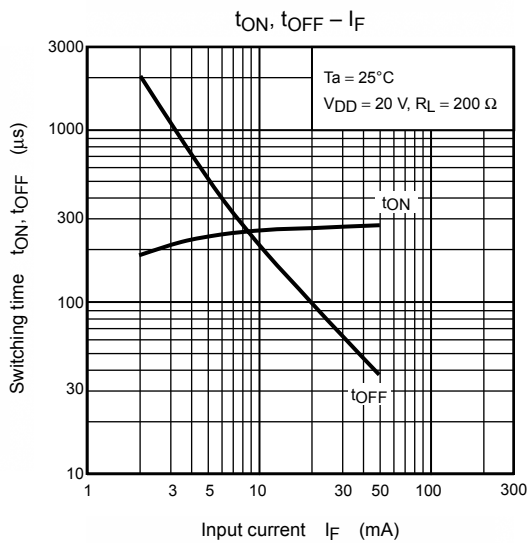
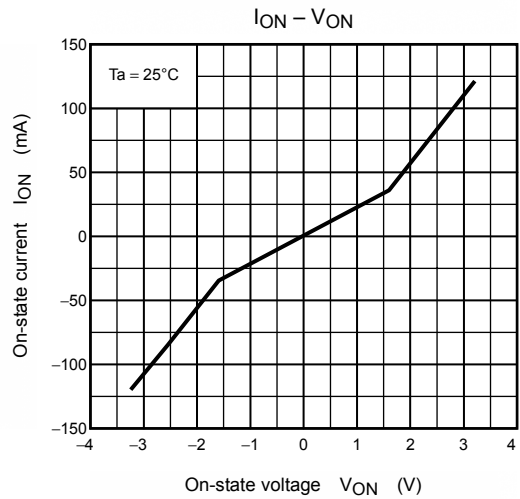
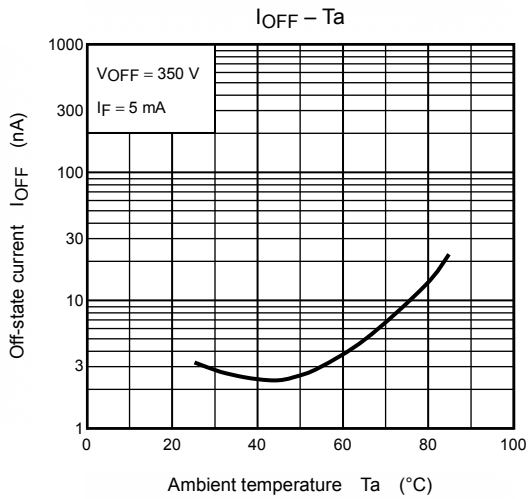
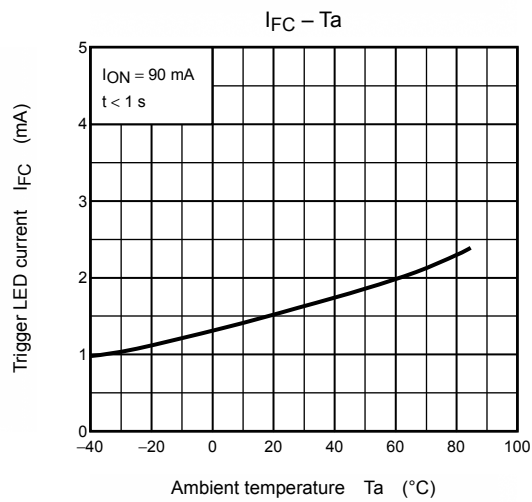
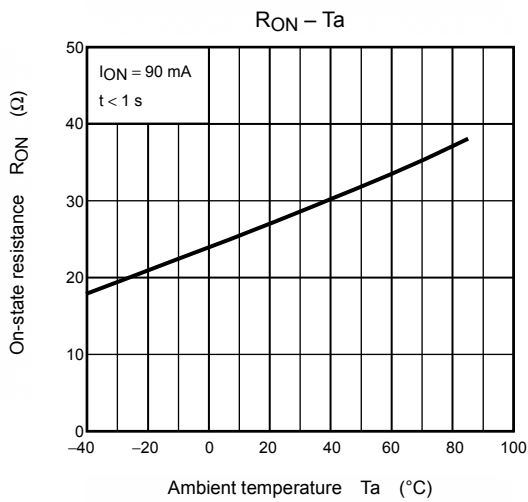
Switching Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Turn-on time	t_{ON}	$R_L = 200 \Omega$ $V_{DD} = 20 \text{ V}, I_F = 5 \text{ mA}$ (Note 2)	—	0.25	0.5	ms
Turn-off time	t_{OFF}		—	0.5	1	ms

Note 2: Switching time test circuit







RESTRICTIONS ON PRODUCT USE

030619EBC

- The information contained herein is subject to change without notice.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA for any infringements of patents or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of TOSHIBA or others.
- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- The products described in this document are subject to the foreign exchange and foreign trade laws.
- TOSHIBA products should not be embedded to the downstream products which are prohibited to be produced and sold, under any law and regulations.
- GaAs(Gallium Arsenide) is used in this product. The dust or vapor is harmful to the human body. Do not break, cut, crush or dissolve chemically.